

LESD8D5.0ET5G ESD PROTECTION DIODE

Discription

The LESD8D5.0ET5G is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

Applications

- I Cellular phones audio
- I MP3 players
- I Digital cameras
- I Portable applications
- I Mobile telephone

Features

- | Low Leakage
- Response Time is Typically < 1 ns
- I IEC61000-4-2 Level 4 ESD Protection
- I These are Pb-Free Devices
- I We declare that the material of product compliance with RoHS requirements.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air discharge Contact discharge		±30 ±30	kV kV
Total Power Dissipation on FR-5 Board (Note 1)	PD	200	mW
@ T _A =25°C			
Junction and Storage Temperature Range	TJ,TSTG	-55 to 150	°C
Lead Solder Temperature – Maximum (10	TL	260	°C
Second Duration)			

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0*0.75*0.62 in.

Ordering information

Device	Marking	Shipping
LESD8D5.0ET5G	DE	10000/Tape&Reel







ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter	
I _{PP}	Maximum Reverse Peak Pulse Current	
V _C	Clamping Voltage @ IPP	
V _{RWM}	Working Peak Reverse Voltage	
I _R	Maximum Reverse Leakage Current @ V_{RWM}	
V _{BR}	Breakdown Voltage @ I _T	
Ι _Τ	Test Current	
١ _F	Forward Current	
V _F	Forward Voltage @ I _F	
P _{pk}	Peak Power Dissipation	
С	Capacitance @ $V_R = 0$ and f = 1.0 MHz	



ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	Vrwm			5	V	
Breakdown Voltage	Vbr	5.6		8	V	I _R = 1mA
Reverse Leakage Current	I _R			1	μA	Vr= 5V
Peak Pulse Current	Ірр			8	А	
				9	V	IPP = 1A (8 x 20µs pulse)
Clamping Voltage	Vc			10.8	V	IPP = 5A (8 x 20µs pulse)
				13	V	IPP = 8A (8 x 20µs pulse)
Capacitance	С			50	pF	V _R = 0V, f = 1MHz





Fig1. Pulse Waveform



Fig 2. Clamping Voltage vs. Peak Pulse Current



Fig 3 .Positive 8kV contact per IEC 61000-4-2



Fig4. Negative 8kV contact per IEC 61000-4-2



Package Outline Dimension



SOD882				
Dim	Min	Тур	Max	
D	0.95	1.00	1.05	
Е	0.55	0.60	0.65	
е	-	0.64	_	
L	0.44	0.49	0.54	
b	0.20	0.25	0.30	
А	0.43	0.48	0.53	
A1	0	_	0. 05	
A3	0.127REF.			
All Dimensions in mm				



Suggested Pad layout



Dimensions	(mm)
С	0.70
G	0.30
Х	0.40
X1	1.10
Y	0.70

单击下面可查看定价,库存,交付和生命周期等信息

>>LRC(乐山无线电)